Reg. No. :

Question Paper Code : 71744

B.E./B.Tech. DEGREE EXAMINATION, APRIL/MAY 2017.

Seventh Semester

Electronics and Communication Engineering

EC 6701 - RF AND MICROWAVE ENGINEERING

(Regulations 2013)

Time : Three hours

Maximum: 100 marks

Answer ALL questions.

PART A — $(10 \times 2 = 20 \text{ marks})$

- 1. Write the frequency range for following IEEE microwave bands?
 - (a) L band
 - (b) S band
 - (c) C band
 - (d) X band
- 2. Give the relation between S and ABCD parameters.
- 3. Define transducer power gain.
- 4. What are waveguide bends? What are the two types of bends?
- 5. List the applications of magic Tee.
- 6. Write the S matrix for 4 port circulator.
- 7 Write the classification of microwave tubes and explain the difference between them.
- 8. What are slow wave structures? Give examples.
- 9. Compare TWT anti Klystron.
- 10. Define guide wavelength.

PART B — $(5 \times 16 = 80 \text{ marks})$

11. (a) Derive the overall network parameters for cascade connection of two port network. Discuss about short circuit, open circuit, h and ABCD low Frequency parameters.

- (b) (i). State and prove the properties of S-matrix.
 - (ii) Explain the symmetry property in a reciprocal network.
- 12. (a) Explain in detail about microstrip line matching network with neat diagram.

Or

- (b) Discuss about the design of T-section and Pi section matching network.
- 13. (a) With neat diagram discuss the characteristics of series Tee and shunt Tee and derive the S matrix.

\mathbf{Or}

- (b) Discuss the principle of operation of any two non reciprocal devices and derive the S parameters.
- 14. (a) With neat diagram explain the operation of two cavity klystron amplifier and derive the equations for velocity modulation process.

\mathbf{Or}

- (b) (i) Give the comparison between Gunn, IMPATT, TRAPATT and Baritt.
 - (ii) Explain the operation of travelling wave tube and write its characteristics.
- 15. (a) Discuss the impedance, wavelength and frequency measurement using slotted line method.

Or

(b) Write short notes on power sensors used for microwave power measurement.